

MJD2955 (PNP) MJD3055 (NPN)



ON Semiconductor®

<http://onsemi.com>

Complementary Power Transistors

DPAK For Surface Mount Applications

Designed for general purpose amplifier and low speed switching applications.

Features

- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves (“-1” Suffix)
- Electrically Similar to MJE2955 and MJE3055
- DC Current Gain Specified to 10 Amperes
- High Current Gain–Bandwidth Product – $f_T = 2.0$ MHz (Min) @ $I_C = 500$ mAdc
- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V
Machine Model, C > 400 V
- Pb–Free Packages are Available

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector–Emitter Voltage	V_{CEO}	60	Vdc
Collector–Base Voltage	V_{CB}	70	Vdc
Emitter–Base Voltage	V_{EB}	5	Vdc
Collector Current	I_C	10	Adc
Base Current	I_B	6	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	$P_{D\dagger}$	20 0.16	W W/ $^\circ\text{C}$
Total Power Dissipation (Note1) @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	1.75 0.014	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction–to–Case	$R_{\theta JC}$	6.25	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction–to–Ambient (Note1)	$R_{\theta JA}$	71.4	$^\circ\text{C}/\text{W}$

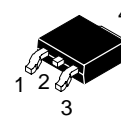
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

†Safe Area Curves are indicated by Figure 1. Both limits are applicable and must be observed.

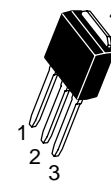
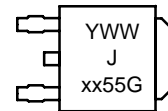
1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

SILICON POWER TRANSISTORS 10 AMPERES 60 VOLTS, 20 WATTS

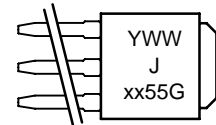
MARKING DIAGRAMS



**DPAK
CASE 369C
STYLE 1**



**DPAK-3
CASE 369D
STYLE 1**



Y = Year
WW = Work Week
Jxx55 = Device Code
x = 29 or 30
G = Pb–Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage (Note 2) (I _C = 30 mA _{dc} , I _B = 0)	V _{CEO(sus)}	60	–	V _{dc}
Collector Cutoff Current (V _{CE} = 30 V _{dc} , I _B = 0)	I _{CEO}	–	50	μA _{dc}
Collector Cutoff Current (V _{CE} = 70 V _{dc} , V _{EB(off)} = 1.5 V _{dc}) (V _{CE} = 70 V _{dc} , V _{EB(off)} = 1.5 V _{dc} , T _C = 150°C)	I _{CEX}	–	0.02 2	mA _{dc}
Collector Cutoff Current (V _{CB} = 70 V _{dc} , I _E = 0) (V _{CB} = 70 V _{dc} , I _E = 0, T _C = 150°C)	I _{CBO}	–	0.02 2	mA _{dc}
Emitter Cutoff Current (V _{BE} = 5 V _{dc} , I _C = 0)	I _{EBO}	–	0.5	mA _{dc}
ON CHARACTERISTICS				
DC Current Gain (Note 2) (I _C = 4 A _{dc} , V _{CE} = 4 V _{dc}) (I _C = 10 A _{dc} , V _{CE} = 4 V _{dc})	h _{FE}	20 5	100 –	–
Collector–Emitter Saturation Voltage (Note 2) (I _C = 4 A _{dc} , I _B = 0.4 A _{dc}) (I _C = 10 A _{dc} , I _B = 3.3 A _{dc})	V _{CE(sat)}	–	1.1 8	V _{dc}
Base–Emitter On Voltage (Note 2) (I _C = 4 A _{dc} , V _{CE} = 4 V _{dc})	V _{BE(on)}	–	1.8	V _{dc}
DYNAMIC CHARACTERISTICS				
Current–Gain – Bandwidth Product (I _C = 500 mA _{dc} , V _{CE} = 10 V _{dc} , f = 500 kHz)	f _T	2	–	MHz

2. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

ORDERING INFORMATION

Device	Package Type	Package	Shipping†
MJD2955	DPAK	369C	75 Units / Rail
MJD2955G	DPAK (Pb–Free)		
MJD2955–001	DPAK–3	369D	
MJD2955–001G	DPAK (Pb–Free)		
MJD2955T4	DPAK	369C	2500 Tape & Reel
MJD2955T4G	DPAK (Pb–Free)		
MJD3055	DPAK		75 Units / Rail
MJD3055G	DPAK (Pb–Free)		
MJD3055T4	DPAK		2500 Tape & Reel
MJD3055T4G	DPAK (Pb–Free)		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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TYPICAL CHARACTERISTICS

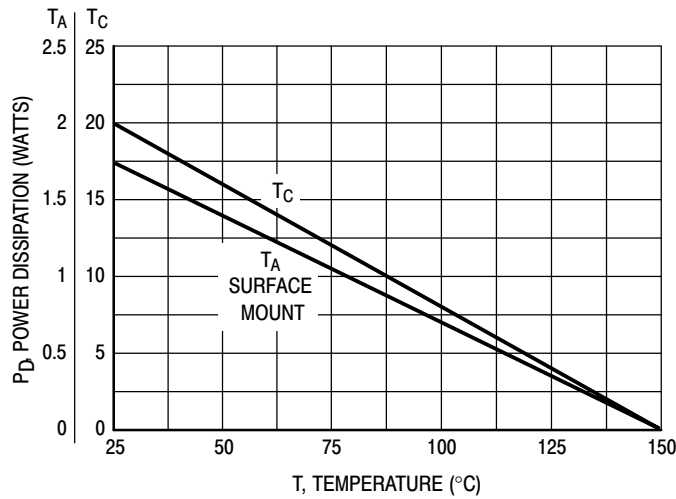


Figure 1. Power Derating

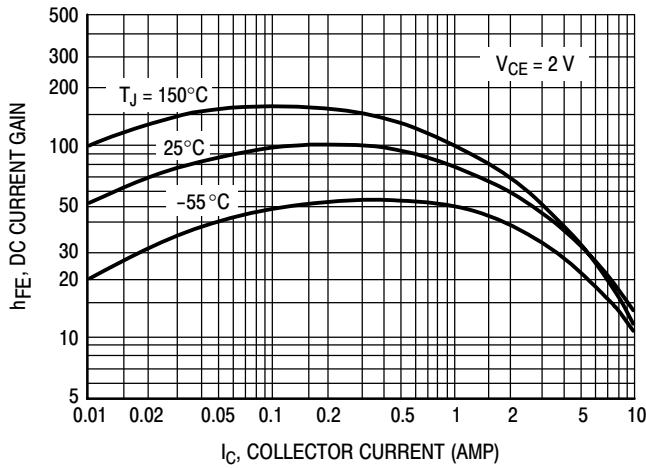


Figure 2. DC Current Gain

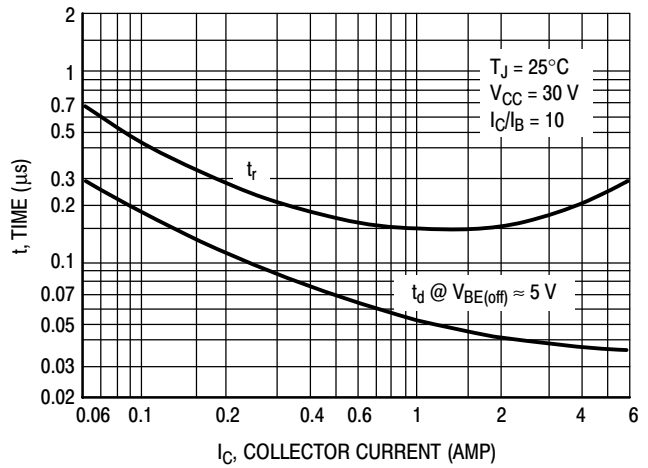


Figure 3. Turn-On Time

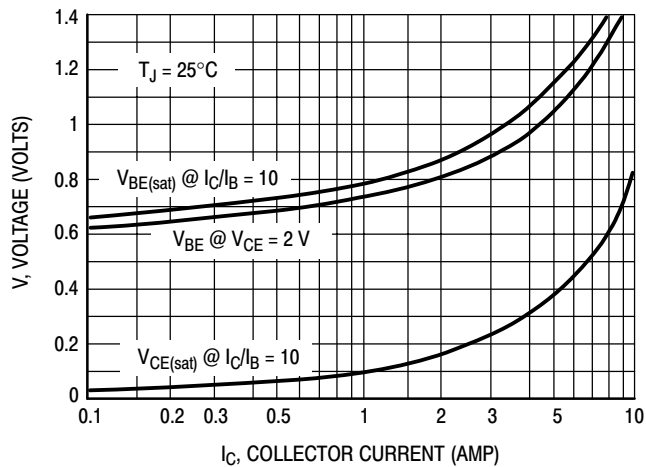


Figure 4. "On" Voltages, MJD3055

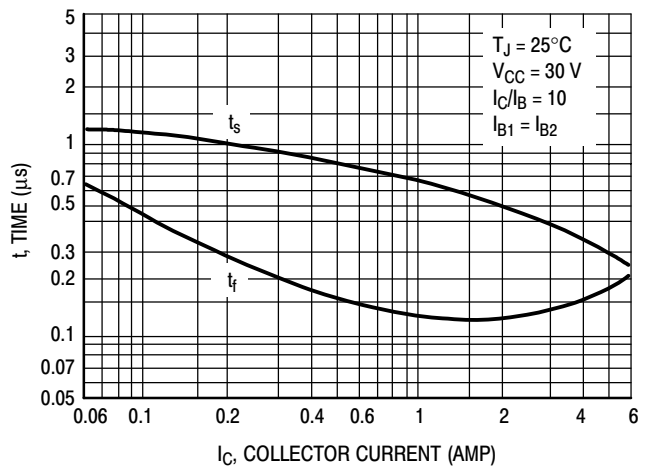


Figure 5. Turn-Off Time

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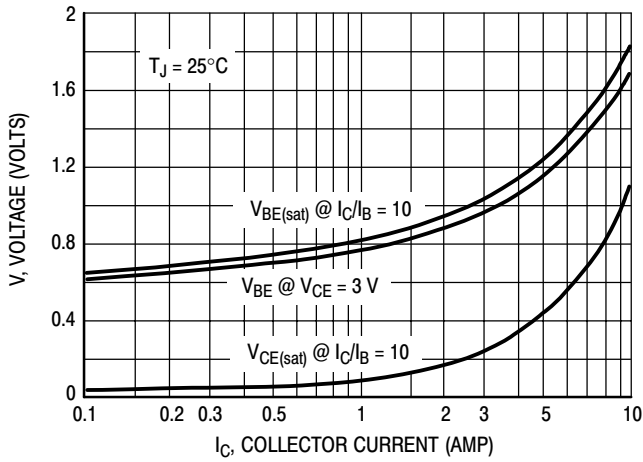


Figure 6. "On" Voltages, MJD2955

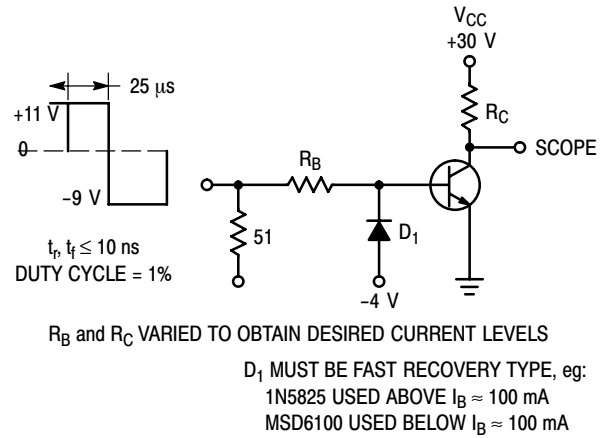


Figure 7. Switching Time Test Circuit

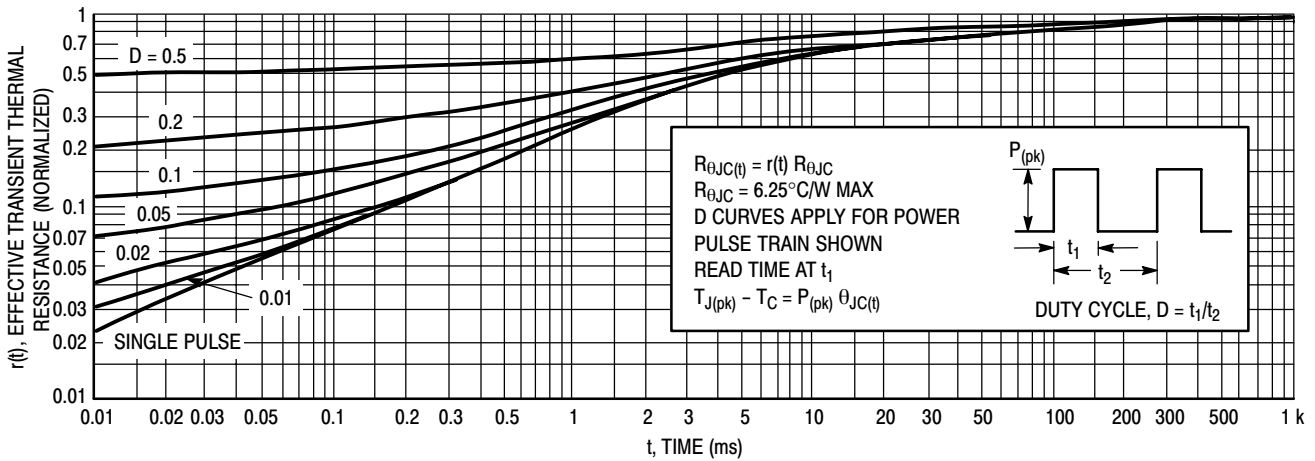


Figure 8. Thermal Response

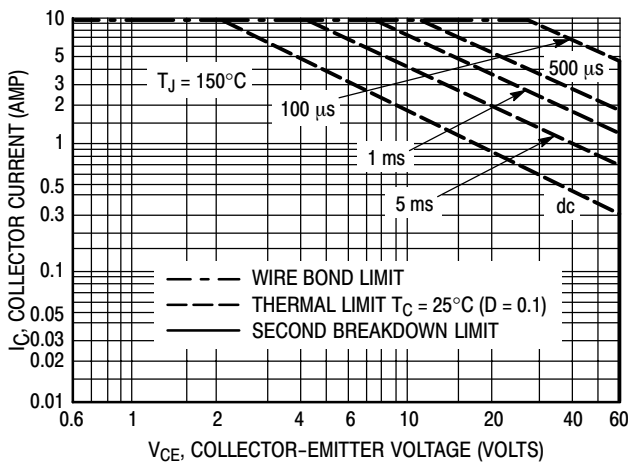


Figure 9. Maximum Forward Bias Safe Operating Area

FORWARD BIAS SAFE OPERATING AREA INFORMATION

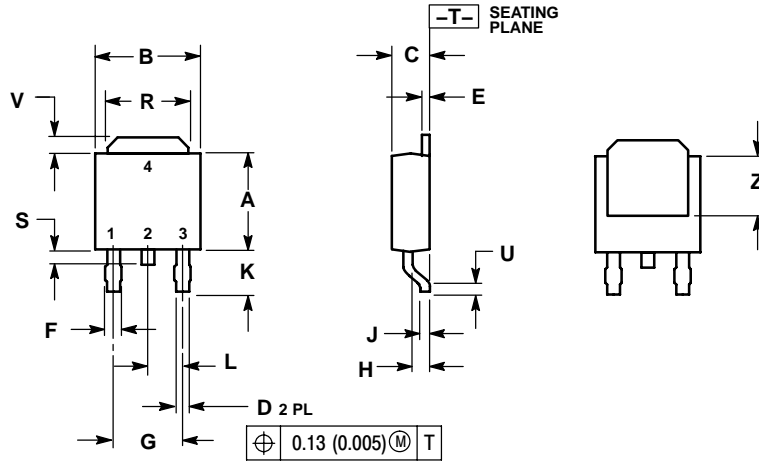
There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 9 is based on $T_{J(pk)} = 150^\circ\text{C}$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^\circ\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 8. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

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PACKAGE DIMENSIONS

DPAK
CASE 369C-01
ISSUE O

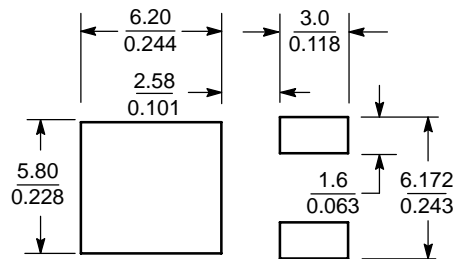


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.245	5.97	6.22
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.180 BSC		4.58 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29 BSC	
R	0.180	0.215	4.57	5.45
S	0.025	0.040	0.63	1.01
U	0.020	---	0.51	---
V	0.035	0.050	0.89	1.27
Z	0.155	---	3.93	---

- STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

SOLDERING FOOTPRINT*



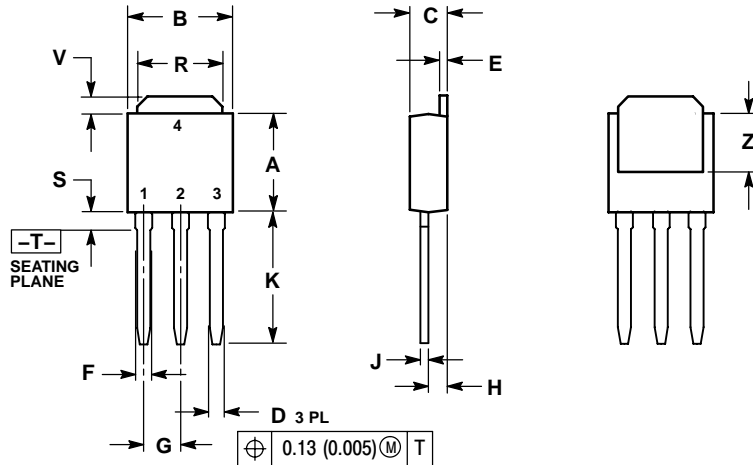
SCALE 3:1 $\left(\frac{\text{mm}}{\text{inches}}\right)$

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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PACKAGE DIMENSIONS

DKPAK-3 CASE 369D-01 ISSUE B



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.245	5.97	6.35
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090 BSC		2.29 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
V	0.035	0.050	0.89	1.27
Z	0.155	---	3.93	---

STYLE 1:

- PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

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